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PATENT



IN THE UNITED STATES PATENT  
AND TRADEMARK OFFICE

Applicant: Kyeong Keun Choi

Serial No.: 10/730,295

Filed: December 8, 2003

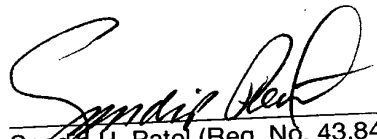
Title: METHOD FOR FORMING HIGH  
RESISTIVE REGION IN  
SEMICONDUCTOR DEVICE

Group Art Unit: 2813

Examiner: David S. Blum

Attorney Docket No.: 29936/39864

) I hereby certify that this paper is being  
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) Mail Stop Amendment, Commissioner for  
) Patents, P.O. Box 1450, Alexandria,  
) Virginia 22313-1450, on **September 19,**  
) **2005.**

  
Sandip H. Patel (Reg. No. 43,848)  
Attorney for Applicant

AMENDMENT "A" AND  
RESPONSE TO OFFICIAL ACTION

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

Dear Sir:

In response to the non-final official action dated June 24, 2005, please amend the above-identified patent application as set forth herein.

Amendments to the claims begin on page 2 of this paper.

Remarks begin on page 5 of this paper.

